



20V N-Channel Enhancement Mode MOSFET

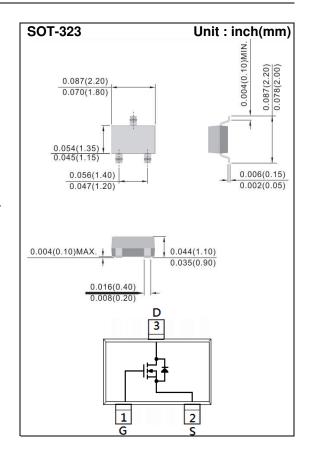
Voltage 20 V Current 1.3A

Features

- RDS(ON) , VGS@4.5V, ID@1.3A<77mΩ
- RDS(ON) , VGS@2.5V, ID@1.0A<90mΩ
- RDS(ON) , VGS@1.8V, ID@0.7A<120mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams
- Marking: C06



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	1.3	Α
Pulsed Drain Current (Note 4)		I _{DM}	5.2	Α
Power Dissipation	T _a =25°C	P _D	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.4	0.67	1.2	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =1.3A	-	66	77	mΩ
		V _{GS} =2.5V, I _D =1.0A	-	75	90	
		V _{GS} =1.8V, I _D =0.7A	-	90	120	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-0.01	1	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =10V, I _D =1.3A, V _{GS} =4.5V ^(Note 1,2)	-	4.6	-	nC
Gate-Source Charge	Q_gs		-	8.0	-	
Gate-Drain Charge	Q_gd		-	1	-	
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V,	-	350	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	29	-	
Switching						
Turn-On Delay Time	td _(on)	\/ 40\/ L 40A	-	4	-	ns
Turn-On Rise Time	tr	V _{DD} =10V, I _D =1.3A,	-	47	-	
Turn-Off Delay Time	td _(off)	V_{GS} =4.5V, R_{G} =6 Ω (Note 1,2)	-	18	-	
Turn-Off Fall Time	tf	K _G -012	-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	0.5	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.75	1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

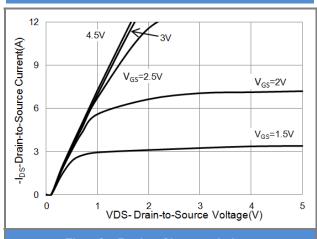


Fig.1 On-Region Characteristics

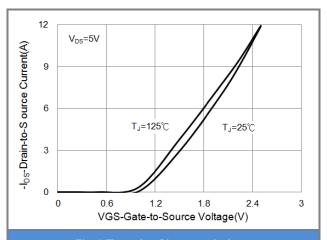


Fig.2 Transfer Characteristics

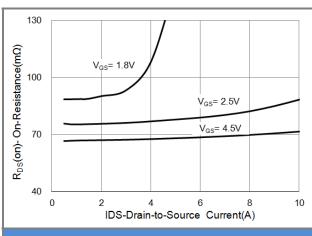


Fig.3 On-Resistance vs. Drain Current

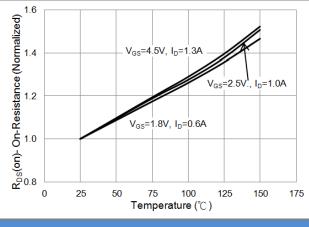


Fig.4 On-Resistance vs. Junction temperature

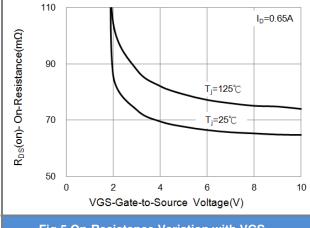


Fig.5 On-Resistance Variation with VGS.

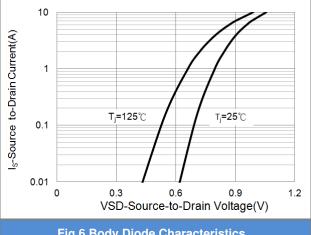


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

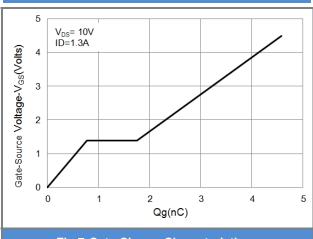


Fig.7 Gate-Charge Characteristics

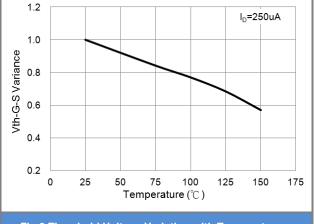


Fig.8 Threshold Voltage Variation with Temperature.

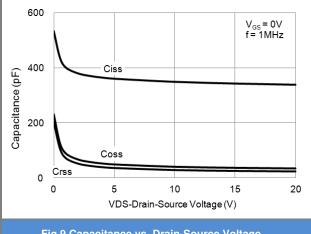


Fig.9 Capacitance vs. Drain-Source Voltage.

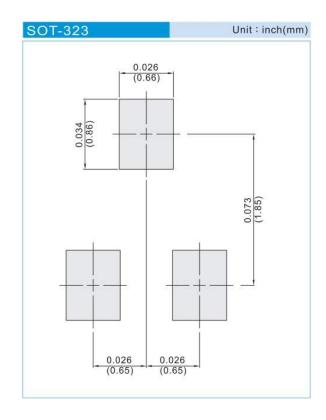




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJC7406_R1_00001	SOT-323	3K pcs / 7" reel	C06	Halogen free
PJC7406_R2_00001	SOT-323	12K pcs / 13" reel	C06	Halogen free

MOUNTING PAD LAYOUT







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